

MI-0018

RF INTENSITY LIMITATIONS IN
MAIN INJECTOR

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RF Intensity Limitation in the Main Injector

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1. I believe that the MR cavities should be fitted with Yt-Ga (Al) orthogonal bias ferrite tuners, replacing existing Ni-Zn ferrite tuners, before transfer to MI.

This should allow higher voltage per cavity and full voltage at any frequency within the tuning range, and increased cavity shunt impedance.

I assume here: (guess)

250 kV per cavity
 $R_{sk} = 800 \text{ k Ohm}$
16 cavities - 4 MV

This should allow broader bandwidth cavity tuning (and detuning) feedback loop. Eliminate the necessity for a "special" or "vernier" cavity for beam-loading compensation of high beam currents.

Using these values:

Cavity Excitation Power

$$P_{cav} = \frac{V^2}{2R_s} = \frac{(250 \times 10^3)^2}{1.6 \times 10^6} = 39 \text{ kW/cav} \quad (\text{call it } 40 \text{ kW})$$

$i_o \equiv i_g$ with no beam

$$i_o = \frac{250 \text{ kV}}{800 \text{ k}\Omega} = 0.31 \text{ Amp}$$

RF power to beam

$$P/\text{proton} = \left[\frac{\text{eV}}{\text{sec}} \right] [1.6 \times 10^{-19}] = (249 \times 10^9) (1.6 \times 10^{-19}) = 4 \times 10^{-8} \frac{\text{Watts}}{\text{Proton}}$$

For 10^{13} protons $P_{beam} + 400 \text{ rW}$

or 25 kW/cav

Number of Protons x 10 ¹³	Beam Power	B.P./ Cavity	Total RF Power per Cavity
1	400 kW	25 kW	65 kW
3	1.2 MW	75	115 kW
6	2.4 MW	150	190
10	4 MW	250	290

Each cavity now driven by one 100 kW (150) operating at approximately 50% efficiency. So somewhere between 3 and 6x10¹³ protons it will become necessary to add an additional rf power source to each cavity. Not difficult to do - we anticipated this need 18 years ago! But water supply may not be adequate and at 6x10¹³, total anode power supply drain will be ~6 MW. Existing anode power supplies ~5 MW and larger tubes required in series tube modulators (probably).

Define

i_o = generator current necessary to develop gap voltage V_o with no beam and cavity tuned to resonance, then with beam generator current:

$$i_g = i_o + i_i \sin \phi_s$$

detuning angle:

$$\tan \phi = - \frac{i_i \cos \phi_s}{i_o}$$

Note: sign of detuning changes with $\phi_s >$ or $< \pi/2$
 $\gamma >$ or $< \gamma_t$

$$P \equiv \frac{\text{Power to Beam}}{\text{Power to cavity}} = \frac{i_i \sin \phi_s}{i_o}$$

$$= - \tan \phi \tan \phi_s$$

The automatic tuning phase detector limits effective detuning angle to about $\pi/3$. Reasonable acceleration rate with adequate "bucket area" establishes ϕ_s near $\pi/4$ or $3\pi/4$. These limits set a practical limit on P of about 1/3.

At 6x10¹³ (1.2x10¹¹ protons/bunch).

Beam current

$$i_{bdc} = \frac{(1.2 \times 10^{11}) (1.6 \times 10^{-19})}{18.8 \times 10^{-9}} = 1 \text{ Amp}$$

Fourier component at rf frequency depending on B.F. ~ 1.5 A

$$\phi_s = 43.6^\circ$$

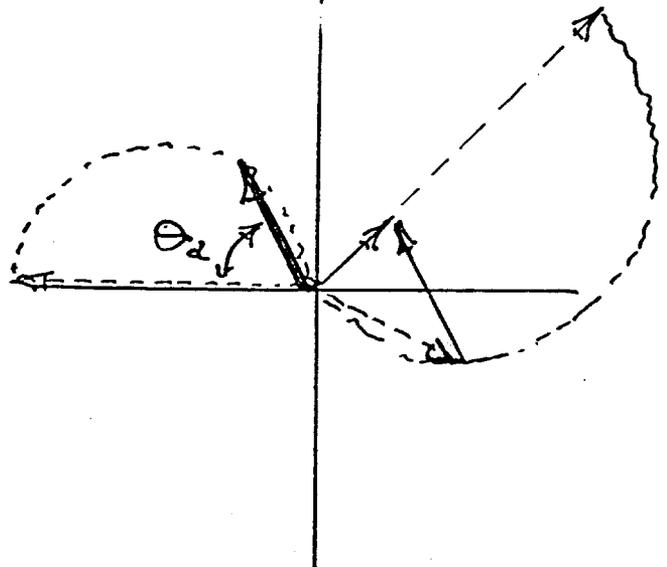
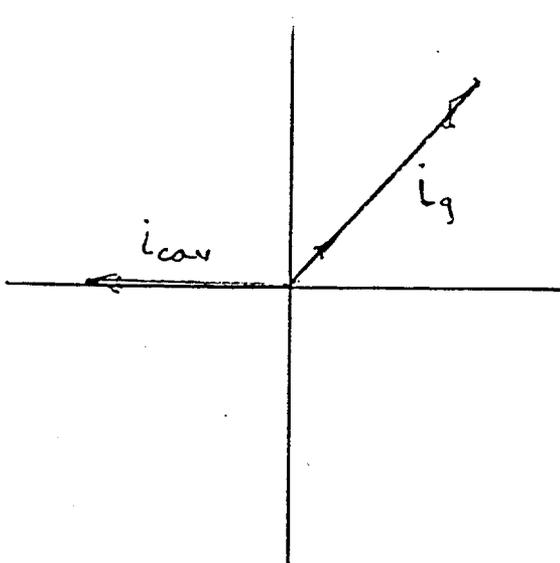
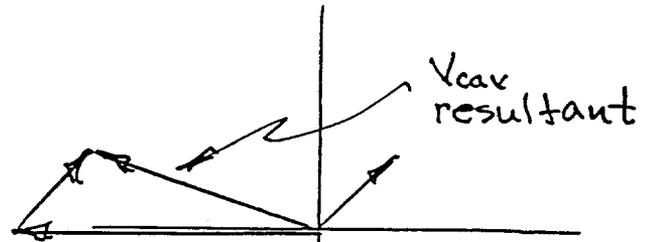
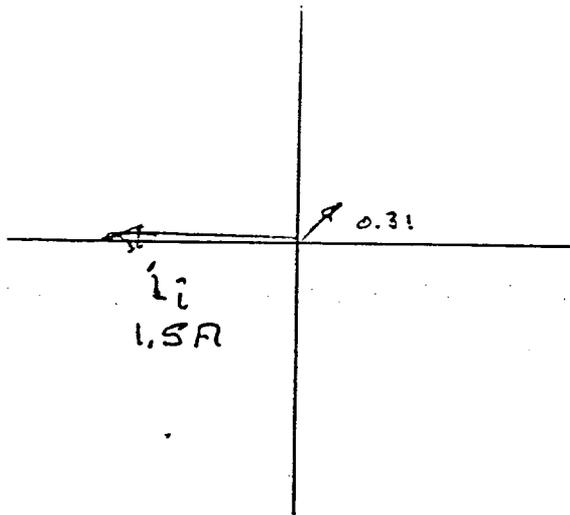
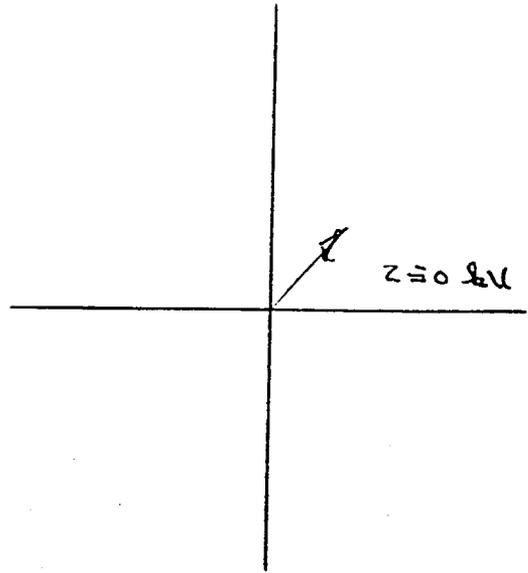
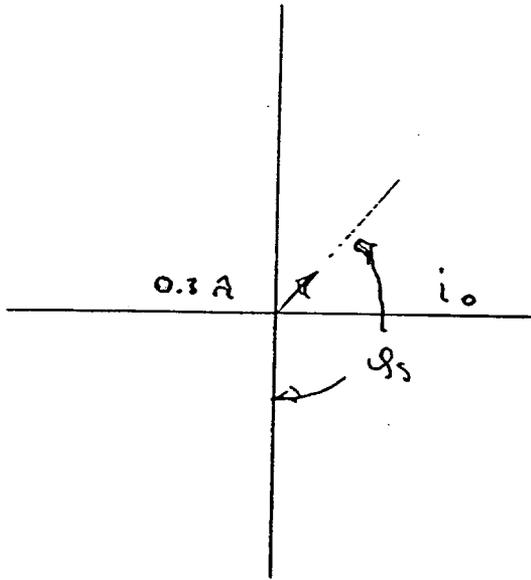
$$\text{Detuning angle } \tan\theta = - \frac{1.5 \cos 43.6}{0.31} = 3.34$$

$$\theta = 73^\circ$$

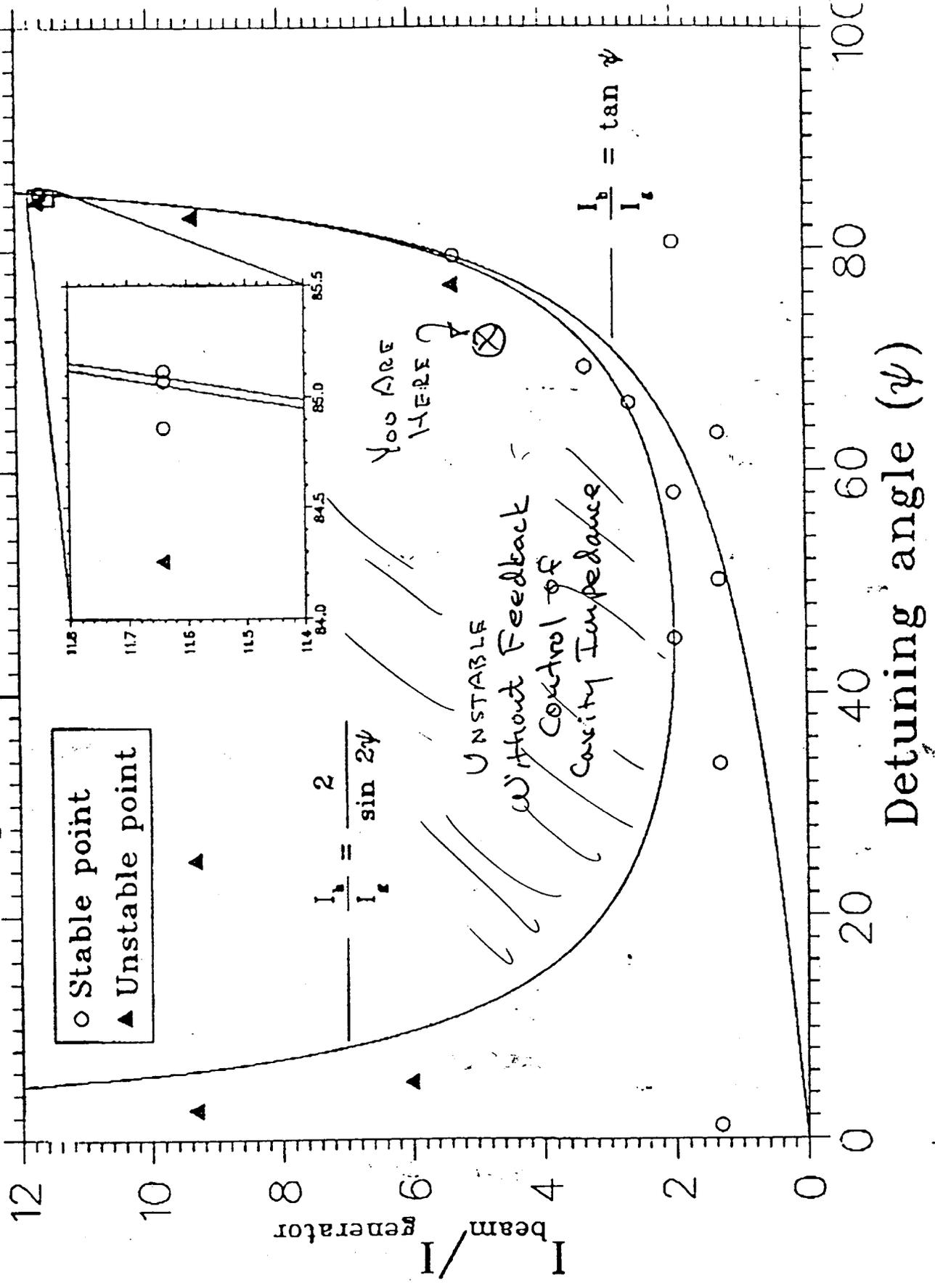
$$\frac{i_l}{i_g} = \frac{1.5}{0.31} = 4.8$$

CURRENT

VOLTAGE



Control Loops Off, Generator Adjusted



Interim Conclusions

- RF cavities probably okay
- With new tuners voltage limited by breakdown or rf heating of ceramic window
- ~250 kV/cav (more would be nice)
- Additional power tube needed on cavities
- This reflects additional load on series tube modulators, probably larger tube
- More anode power needed - ~ 30 kV @ 50A
- With improved tuners, feedback bandwidth probably (can be made to be) adequate for transient beam loading compensation
- At 6×10^{13} the system is edging into rough ground w.r.t. stability

Proceed carefully!

Recent Developments

Historically rf cavities have been tuned using Mn-Zn ferrite rings. Biassing flux (or current) was parallel to the rf flux (or current).

This created problems.

Ferrite Q ranges 100 -> 1000.

LANL pioneered the use of Yt Ga or other μ -wave ferrite, with orthogonal bias.

The ferrite μ_r is lower - 1.5 to 3.5
but Q is much higher so more
energy can be stored per unit volume

This allows higher gap voltages per cavity - fewer cavities - fewer stability problems. Development condition. Stay tuned.